

# **General Description**

The WST2335 is the highest performance trench P-ch MOSFET with extreme high cell density,which provide excellent  $R_{\text{DSON}}$  and gate charge for most of the synchronous buck converter applications .

The WST2335 meet the RoHS and Green Product requirement, with full function reliability approved.

#### **Features**

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- Green Device Available

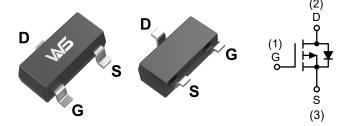
# **Product Summery**

BV <sub>DSS</sub>	R <sub>DSON</sub>	l <sub>D</sub>
-20V	50mΩ	-4.4A

### **Applications**

- High Frequency Point-of-Load Synchronous Buck Converter for MB/NB/UMPC/VGA
- Networking DC-DC Power System
- Load Switch

# **SOT-23L Pin Configuration**



# **Absolute Maximum Ratings**

Symbol	Parameter	Rating	Units	
$V_{DS}$	Drain-Source Voltage	-20	V	
$V_{GS}$	Gate-Source Voltage	±12	V	
I <sub>D</sub> @T <sub>C</sub> =25℃	Continuous Drain Current, V <sub>GS</sub> @ -4.5V <sup>1</sup>	-4.4	Α	
I <sub>D</sub> @T <sub>C</sub> =70°C	Continuous Drain Current, V <sub>GS</sub> @ -4.5V <sup>1</sup>	-2.8	А	
I <sub>DM</sub>	Pulsed Drain Current <sup>2</sup>	-14	Α	
P <sub>D</sub> @T <sub>A</sub> =25°C	Total Power Dissipation <sup>3</sup>	1	W	
T <sub>STG</sub>	Storage Temperature Range	-55 to 150	$^{\circ}$	
TJ	Operating Junction Temperature Range	-55 to 150	$^{\circ}$	

#### **Thermal Data**

Symbol	Parameter	Тур.	Max.	Unit
R <sub>0JA</sub>	Thermal Resistance Junction-Ambient <sup>1</sup>		125	°C/W
$R_{ heta JC}$	Thermal Resistance Junction-Case <sup>1</sup>		80	°C/W



# Electrical Characteristics (T<sub>J</sub>=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit	
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V , I <sub>D</sub> =-250uA	-20			V	
$\triangle BV_{DSS}/\triangle T_{J}$	BV <sub>DSS</sub> Temperature Coefficient	Reference to 25℃ , I <sub>D</sub> =-1mA		-0.014		V/℃	
В	Static Drain-Source On-Resistance <sup>2</sup>	V <sub>GS</sub> =-4.5V , I <sub>D</sub> =-3A		50	60	mΩ	
$R_{DS(ON)}$		V <sub>GS</sub> =-2.5V , I <sub>D</sub> =-2A		73	90		
$V_{GS(th)}$	Gate Threshold Voltage	V <sub>GS</sub> =V <sub>DS</sub> . In =-250uA	-0.5	-0.8	-1.2	V	
$\triangle V_{GS(th)}$	V <sub>GS(th)</sub> Temperature Coefficient	VGS-VDS , ID250UA		3.95		mV/℃	
	Drain Source Leakage Current	$V_{DS}$ =-16V , $V_{GS}$ =0V , $T_{J}$ =25 $^{\circ}$ C			-1		
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =-16V , V <sub>GS</sub> =0V , T <sub>J</sub> =55℃			-5	uA	
I <sub>GSS</sub>	Gate-Source Leakage Current	$V_{GS}$ = $\pm 12V$ , $V_{DS}$ = $0V$			±100	nA	
gfs	Forward Transconductance	V <sub>DS</sub> =-5V , I <sub>D</sub> =-3A		12.8		S	
Qg	Total Gate Charge (-4.5V)			10.2	14.3		
$Q_{gs}$	Gate-Source Charge	V <sub>DS</sub> =-15V , V <sub>GS</sub> =-4.5V , I <sub>D</sub> =-3A		1.89	2.6	nC	
$Q_{gd}$	Gate-Drain Charge			3.1	4.3		
T <sub>d(on)</sub>	Turn-On Delay Time			5.6	11.2		
Tr	Rise Time	V <sub>DD</sub> =-10V , V <sub>GS</sub> =-4.5V ,		40.8	73		
T <sub>d(off)</sub>	Turn-Off Delay Time	$R_G=3.3\Omega$ , $I_D=-3A$		18	36	ns ns	
T <sub>f</sub>	Fall Time			33.6	67		
C <sub>iss</sub>	Input Capacitance			857	1200		
Coss	Output Capacitance	V <sub>DS</sub> =-15V , V <sub>GS</sub> =0V , f=1MHz		114	160	160 pF	
C <sub>rss</sub>	Reverse Transfer Capacitance			108	151	151	

### **Diode Characteristics**

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
Is	Continuous Source Current <sup>1,4</sup>	V =V =0V Force Current			-4.3	Α
I <sub>SM</sub>	Pulsed Source Current <sup>2,4</sup>	V <sub>G</sub> =V <sub>D</sub> =0V , Force Current			-14	Α
$V_{SD}$	Diode Forward Voltage <sup>2</sup>	$V_{GS}$ =0V , $I_{S}$ =-1A , $T_{J}$ =25 $^{\circ}$ C			-1	V
t <sub>rr</sub>	Reverse Recovery Time			21.8		nS
Q <sub>rr</sub>	Reverse Recovery Charge	lF=-3A , dl/dt=100A/µs , T <sub>J</sub> =25℃		6.9		nC

#### Note:

- 1. The data tested by surface mounted on a 1 inch<sup>2</sup> FR-4 board with 2OZ copper, t<10 sec.
- 2.The data tested by pulsed , pulse width  $\,\leq\,$  300us , duty cycle  $\,\leq\,$  2%
- 4. The data is theoretically the same as  $I_D$  and  $I_{DM}$ , in real applications, should be limited by total power dissipation.



# **Typical Characteristics**

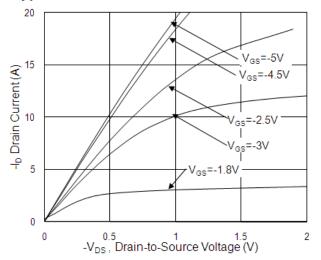


Fig.1 Typical Output Characteristics

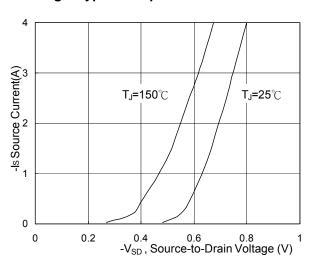


Fig.3 Forward Characteristics of Reverse

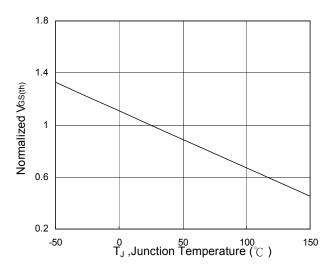


Fig.5 Normalized V<sub>GS(th)</sub> vs. T<sub>J</sub>

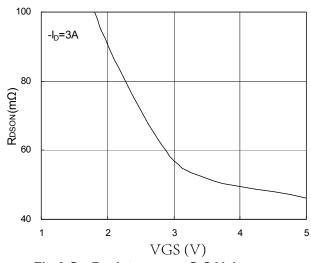


Fig.2 On-Resistance vs. G-S Voltage

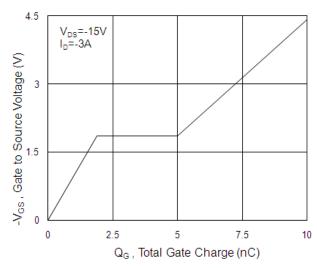


Fig.4 Gate-charge Characteristics

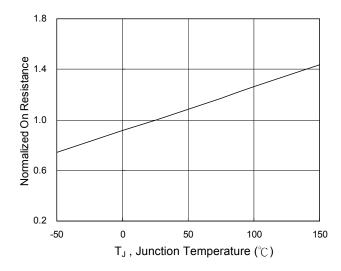
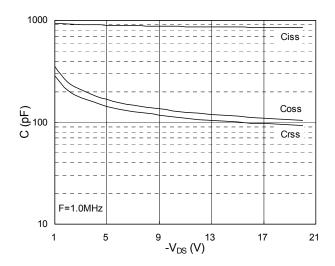


Fig.6 Normalized R<sub>DSON</sub> vs. T<sub>J</sub>





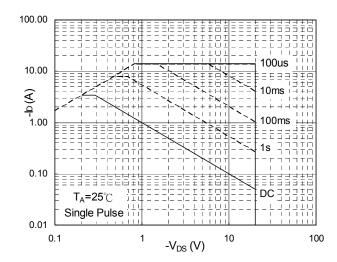


Fig.7 Capacitance

Fig.8 Safe Operating Area

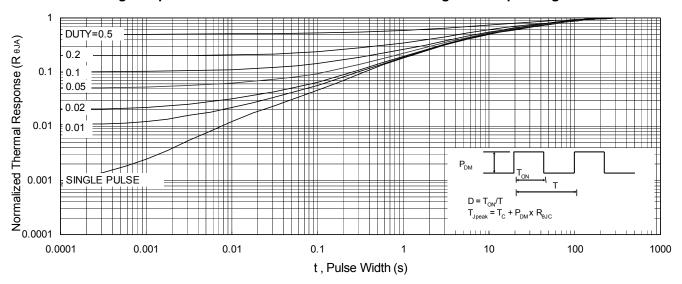
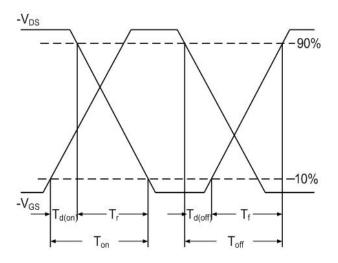


Fig.9 Normalized Maximum Transient Thermal Impedance



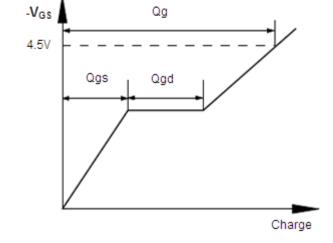
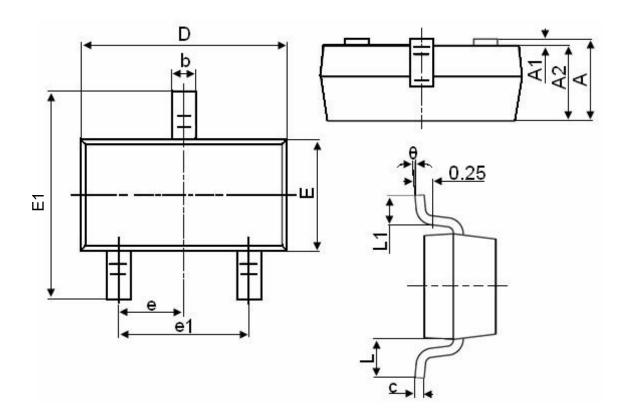


Fig.10 Switching Time Waveform

Fig.11 Gate Charge Waveform



# **Packaging information**



Cyrreb ol	Dimensions in Millimeters			
Symbol	MIN.	MAX.		
Α	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
Е	1.200	1.400		
E1	2.250	2.550		
е	0.99	0.950TYP		
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	0°	8°		



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